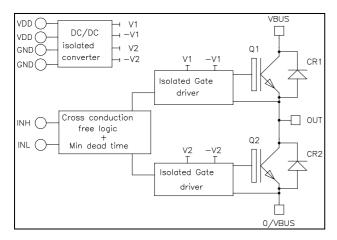
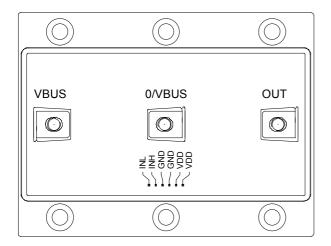


Phase leg Intelligent Power Module





$V_{CES} = 1200V$ $I_{C} = 300A$ @ Tc = 80°C

Application

- Motor control
- Uninterruptible Power Supplies
- Switched Mode Power Supplies
- Amplifier

Features

- Trench + Field Stop IGBT 3 Technology
 - Low voltage drop
 - Low tail current
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated

• Integrated Fail Safe IGBT Protection (Driver)

- Top Bottom input signals Interlock
- Isolated DC/DC Converter
- Low stray inductance
- M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Very high noise immunity (common mode rejection > 25kV/μs)
- Galvanic Isolation: 3750V for the optocoupler 2500V for the transformer
- 5V logic level with Schmitt-trigger Input
- Single V_{DD}=5V supply required
- Secondary auxiliary power supplies internally generated (15V, -6V)
- Optocoupler qualified to AEC-Q100 test guidelines
- RoHS compliant

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All ratings @ $T_j = 25$ °C unless otherwise specified

1. Inverter Power Module

Absolute maximum ratings

| Symbol | Parameter | | Max ratings | Unit |
|-----------|---------------------------------------|----------------------|--------------|------|
| V_{CES} | Collector - Emitter Breakdown Voltage | | 1200 | V |
| ī | Continuous Collector Current | $T_C = 25^{\circ}C$ | 440 | |
| I_{C} | T _C = | $T_C = 80^{\circ}C$ | 300 | Α |
| I_{CM} | Pulsed Collector Current | $T_C = 25^{\circ}C$ | 600 | |
| P_{D} | Maximum Power Dissipation | $T_C = 25$ °C | 1400 | W |
| RBSOA | Reverse Bias Safe Operating Area | $T_j = 125^{\circ}C$ | 600A @ 1150V | |

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|--------------------------------|---------------------|-----|-----|-----|------|
| I _{CES} | Zero Gate Voltage Collector Current | $V_{GE} = 0V$ | $T_j = 25^{\circ}C$ | | | 500 | μΑ |
| | | $V_{CE} = 1200V$ | $T_j = 125$ °C | | | 750 | |
| V _{CE(sat)} | Collector Emitter Saturation Voltage | $V_{\rm DD} = V_{\rm IN} = 5V$ | $T_j = 25$ °C | | 1.7 | 2.1 | V |
| | | $I_{\rm C} = 300A$ | $T_j = 125$ °C | | 2 | | V |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|------------------|-------------------------------------|--|-----|------|------|---------|
| Cies | Input Capacitance | $V_{GE} = 0V$ | | 21 | | |
| C_{oes} | Output Capacitance | $V_{CE} = 25V$ | | 1.12 | | nF |
| C_{res} | Reverse Transfer Capacitance | f = 1MHz | | 0.96 | | |
| $T_{\rm r}$ | Rise Time | Inductive Switching (25°C) | | 40 | | ng |
| T_{f} | Fall Time | $V_{DD} = V_{IN} = 5V$ $V_{Bus} = 600V$; $I_C = 300A$ | | 70 | | ns |
| $T_{\rm r}$ | Rise Time | Inductive Switching (125°C) | | 45 | | |
| $T_{\rm f}$ | Fall Time | $V_{DD} = V_{IN} = 5V$ | | 90 | | ns |
| Eon | Turn-on Switching Energy | $V_{\text{Bus}} = 600V$ $I_{\text{C}} = 300A$ | | 28 | | T |
| E_{off} | Turn-off Switching Energy | | | 32 | | mJ |
| I_{sc} | Short Circuit data | $V_{DD} = V_{IN} = 5V; V_{Bus} = 900V$ $t_p \le 10 \mu s; T_j = 125 ^{\circ} C$ | | 1200 | | A |
| R_{thJC} | Junction to Case thermal resistance | | | | 0.09 | °C/W |



Reverse diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit | |
|-----------------|--|---------------------------|---------------------------------|-----------------------|------------------------|------|------|--|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 1200 | | | V | |
| I_{RM} | Maximum Reverse Leakage Current | V _R =1200V | $T_{\rm j} = 25^{\circ}{\rm C}$ | | | 250 | μA | |
| $I_{\rm F}$ | DC Forward Current | | $T_i = 125$ °C Tc = 80°C | | 300 | 500 | A | |
| 17 | V_F Diode Forward Voltage $I_F = 300A$ | 1 2004 | $T_i = 25^{\circ}C$ | | 1.6 | 2.1 | V | |
| V _F | | $I_F = 300A$ | $T_i = 125^{\circ}C$ | | 1.6 | | V | |
| t _{rr} | Reverse Recovery Time | $I_F = 300A$ $V_R = 600V$ | $T_j = 25$ °C | | 170 | | ns | |
| v _{rr} | Reverse Recovery Time | | $T_{j} = 125^{\circ}C$ | | 280 | | 113 | |
| Q_{rr} | Reverse Recovery Charge | | $T_j = 25$ °C | | 28 | | μС | |
| Qrr | Reverse Recovery Charge | | | $di/dt = 3500A/\mu s$ | $T_{j} = 125^{\circ}C$ | | 56 | |
| Г | Reverse Recovery Energy | | $T_j = 25$ °C | | 12 | | m I | |
| E_{rr} | | | $T_{j} = 125^{\circ}C$ | | 22 | | mJ | |
| R_{thJC} | Junction to Case Thermal Resistance | | _ | | | 0.16 | °C/W | |

2. Driver

Absolute maximum ratings

| Symbol | i | Parameter | Max ratings | Unit |
|---------------------|-----------------------------|--|-------------|------|
| $V_{ m DD}$ | Supply Voltage | | 5.5 | V |
| V_{INi} | Input signal voltage i=L, H | | 5.5 | ` |
| I _{VDDmax} | Maximum Supply current | $V_{INi} = 0V$, $i = L \& H$ | 0.35 | |
| | | $V_{DD} = 5V$, $V_{INH} = /V_{INL}$; $F_{out} = 45kHz$ | 2 | A |
| f_{max} | Maximum Switching Frequen | ncy | 45 | kHz |

Driver Electrical Characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit |
|------------------------|--|--|------|-------|-----|-----------|
| $V_{ m DD}$ | Operating Supply Voltage | | 4.5 | 5 | 5.5 | V |
| V _{INi(max)} | Maximum Input Voltage | | -0.5 | 5 | 5.5 | |
| V _{INi (th+)} | Positive Going Threshold Voltage | i = L. H | | 3.2 | | V |
| $V_{INi(th-)}$ | Negative Going Threshold Voltage | , II | | 1 | | |
| R _{INi} | Input Resistance * | 1 [| | 1 | | kΩ |
| $T_{d(on)}$ | Turn On delay time | Driver + IGBT | | 1100° | | |
| D_{T} | Built in dead time | | | 600 | | ns |
| $T_{d(off)}$ | Turn Off delay time | Driver + IGBT | | 750 | | |
| PWD | Pulse Width Distortion | | | | 300 | |
| PDD | Propagation Delay Difference between any two driver | T _{d(on)} - T _{d(off)} | -350 | | 350 | ns |
| V_{ISOL} | Primary to Secondary Isolation | | 2500 | | · | V_{RMS} |

^{*} Low impedance guarantees good noise immunity.

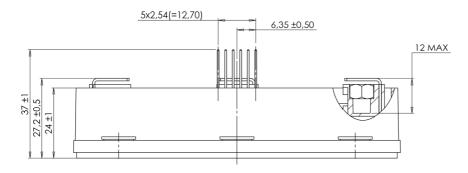
[•] Including built in dead time.

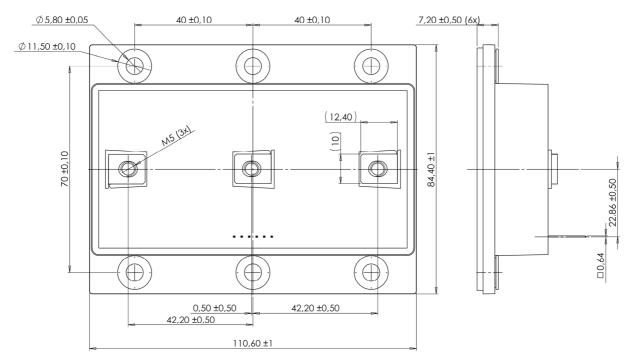


3. Package characteristics

| Symbol | Characteristic | | | Min | Typ | Max | Unit | | |
|------------------|--|---------------|----|------|-----|-----|--------|--|--|
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz | | | 4000 | | | V | | |
| T_{J} | Operating junction temperature range | | | -40 | | 150 | | | |
| T _{OP} | Operating Ambient Temperature | | | -40 | | 85 | °C | | |
| T_{STG} | Storage Temperature Range | | | -40 | | 100 | | | |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | | | |
| Torque | Mounting targue To heatsink | | M5 | 2 | | 4.7 | N.m | | |
| Torque | Mounting torque For terminals | For terminals | M5 | 2 | | 4 | 11.111 | | |
| Wt | Package Weight | | | | 550 | | g | | |

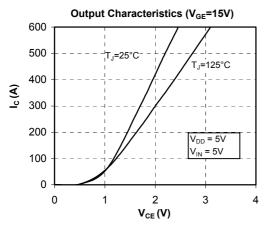
4. LP8 Package outline (dimensions in mm)

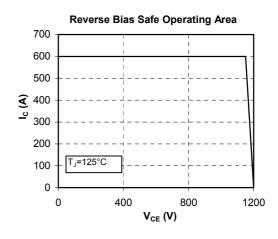


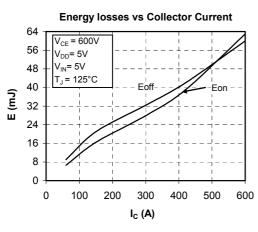


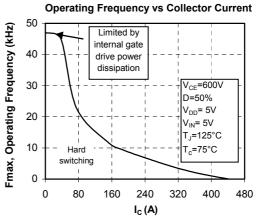


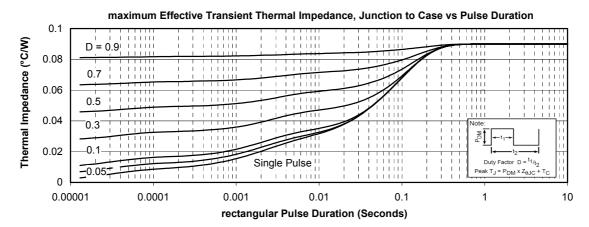
Typical IGBT Performance Curve





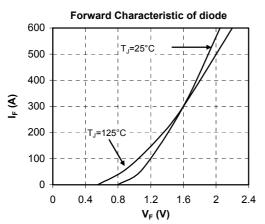


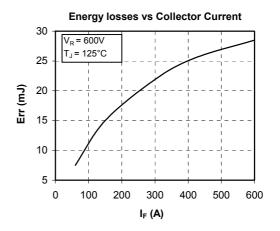


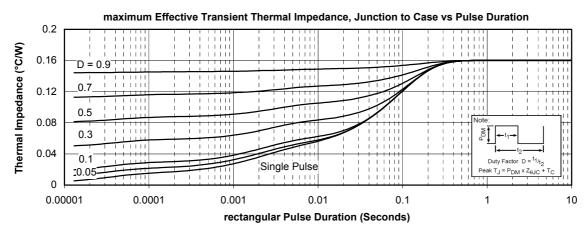




Typical diode Performance Curve









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